CSD18533Q5A 60V N 沟道 NexFET™ 功率金属氧化物半导体场效应晶体管 (MOSFET)

1 特性

- 超低 Qg 和 Qgd
- 低热阻
- 雪崩额定值
- 逻辑电平
- 无铅引脚镀层
- 符合 RoHS 标准
- 无卤素
- 小外形尺寸无引线 (SON) 5mm x 6mm 塑料封装

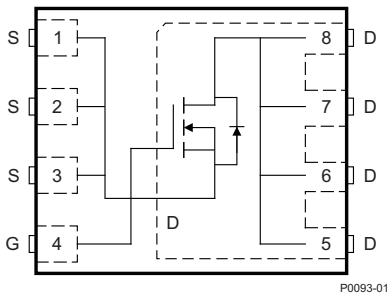
2 应用范围

- 直流 - 直流转换
- 次级侧同步整流器
- 电机控制

3 说明

这款 4.7mΩ、60V、SON 5mm × 6mm NexFET™ 功率 MOSFET 被设计成在功率转换应用中最大限度地降低功率损耗。

俯视图



产品概要

T_A = 25°C		典型值		单位
V_{DS}	漏源电压	60		V
Q_g	栅极电荷总量 (10V)	29		nC
Q_{gd}	栅极电荷（栅极到漏极）	5.4		nC
$R_{DS(on)}$	漏源导通电阻	V_{GS} = 4.5V	6.5	mΩ
		V_{GS} = 10V	4.7	mΩ
$V_{GS(th)}$	阈值电压	1.9		V

订购信息(1)

器件	数量	介质	封装	出货
CSD18533Q5A	2500	13 英寸卷带	SON 5mm × 6mm 塑料封装	卷带封装
CSD18533Q5AT	250	7 英寸卷带		

(1) 要了解所有可用封装，请见数据表末尾的可订购产品附录。

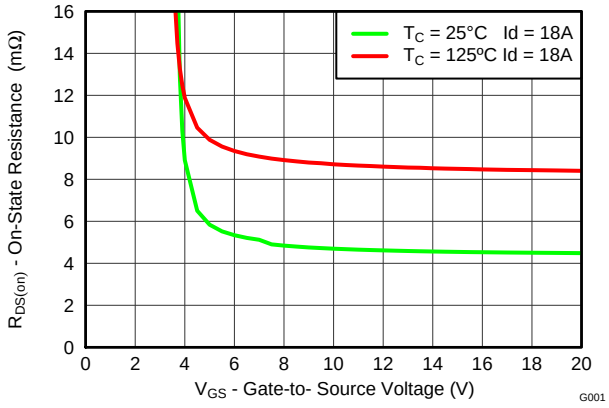
绝对最大额定值

T_A = 25°C		值	单位
V_{DS}	漏源电压	60	V
V_{GS}	栅源电压	±20	V
I_D	持续漏极电流（受封装限制），T_C = 25°C 时测得	100	A
	持续漏极电流（受芯片限制），T_C = 25°C 时测得	103	
	持续漏极电流，T_A = 25°C 时测得(1)	17	
I_{DM}	脉冲漏极电流，T_A = 25°C 时测得(2)	267	A
P_D	功率耗散(1)	3.2	W
	功耗，TC = 25°C	116	
T_J, T_{stg}	运行结温和储存温度范围	-55 至 150	°C
E_{AS}	雪崩能量，单脉冲 I_D = 53A，L = 0.1mH，R_G = 25Ω	140	mJ

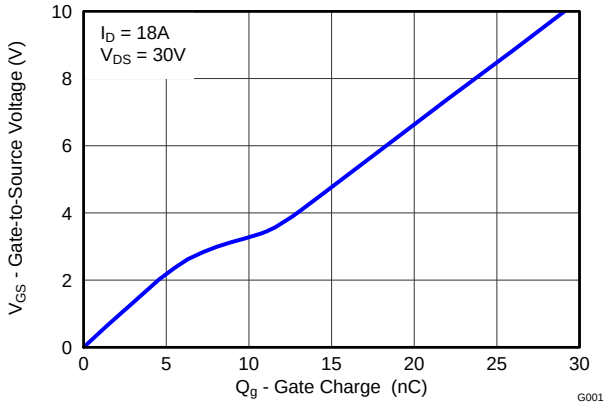
(1) $R_{\theta JA}$ = 40°C/W，这是在厚度为 0.06 英寸的环氧板 (FR4) 印刷电路板 (PCB) 上的 1 英寸^2 2 盎司 的铜过渡垫片上测得的典型值。

(2) 最大 $R_{\theta JC}$ = 1.3°C/W，脉冲持续时间 ≤100μs，占空比 ≤1%

$R_{DS(on)}$ 与 V_{GS} 间的关系



栅极电荷



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4 修订历史记录

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (May 2013) to Revision B **Page**

- 已添加 器件编号至标题 ... 1
- 已添加 外壳温度保持在 25°C 时的最大功耗一行 ... 1
- 已更新脉冲电流条件 ... 1
- Changed Figure 1 to normalized $R_{\theta JC}$ curve ... 4
- Updated SOA in Figure 10 ... 6

Changes from Original (September 2012) to Revision A **Page**

- 已将脉冲漏极电流增加至 267A ... 1
- Changed the $R_{\theta JC}$ MAX value From: 2.3°C/W to 1.3°C/W ... 3
- Changed From: Max $R_{\theta JA}$ = 121°C/W To: Max $R_{\theta JA}$ = 125°C/W ... 4
- Changed Typ Rth_{JA} = 99°C/W To:Rth_{JA} = 100°C/W in Figure 1 ... 4
- 已添加“建议模板开口”部分 ... 9

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5 Specifications

5.1 Electrical Characteristics

(T_A = 25°C unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC CHARACTERISTICS						
BV_{DSS}	Drain-to-Source Voltage	V_{GS} = 0 V, I_D = 250 µA	60			V
I_{DSS}	Drain-to-Source Leakage Current	V_{GS} = 0 V, V_{DS} = 48 V			1	µA
I_{GSS}	Gate-to-Source Leakage Current	V_{DS} = 0 V, V_{GS} = 20 V			100	nA
$V_{GS(th)}$	Gate-to-Source Threshold Voltage	V_{DS} = V_{GS}, I_D = 250 µA	1.5	1.9	2.3	V
$R_{DS(on)}$	Drain-to-Source On-Resistance	V_{GS} = 4.5 V, I_D = 18 A		6.5	8.5	mΩ
		V_{GS} = 10 V, I_D = 18 A		4.7	5.9	mΩ
g_{fs}	Transconductance	V_{DS} = 30 V, I_D = 18 A		122		S
DYNAMIC CHARACTERISTICS						
C_{iss}	Input Capacitance	V_{GS} = 0 V, V_{DS} = 30 V, f = 1 MHz		2200	2750	pF
C_{oss}	Output Capacitance			292	365	pF
C_{rss}	Reverse Transfer Capacitance			7	9	pF
R_G	Series Gate Resistance			1.3	2.6	Ω
Q_g	Gate Charge Total (4.5 V)	V_{DS} = 30 V, I_D = 18 A		14	18	nC
Q_g	Gate Charge Total (10 V)			29	36	nC
Q_{gd}	Gate Charge Gate-to-Drain			5.4		nC
Q_{gs}	Gate Charge Gate-to-Source			6.6		nC
$Q_{g(th)}$	Gate Charge at Vth			4.7		nC
Q_{oss}	Output Charge	V_{DS} = 30 V, V_{GS} = 0 V		31		nC
$t_{d(on)}$	Turn On Delay Time	V_{DS} = 30 V, V_{GS} = 10 V, I_{DS} = 18 A, R_G = 0 Ω		5.2		ns
t_r	Rise Time			5.5		ns
$t_{d(off)}$	Turn Off Delay Time			15		ns
t_f	Fall Time			2.0		ns
DIODE CHARACTERISTICS						
V_{SD}	Diode Forward Voltage	I_{SD} = 18 A, V_{GS} = 0 V		0.8	1	V
Q_{rr}	Reverse Recovery Charge	V_{DS}= 30 V, I_F = 18 A, di/dt = 300 A/µs		68		nC
t_{rr}	Reverse Recovery Time			40		ns

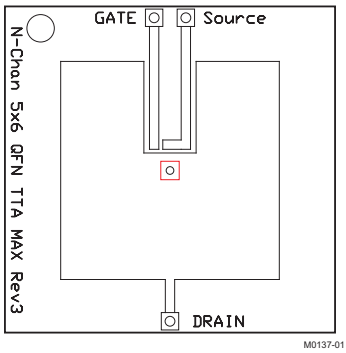
5.2 Thermal Information

(T_A = 25°C unless otherwise stated)

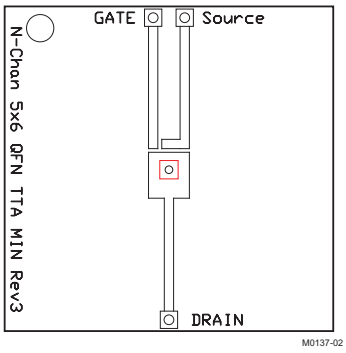
THERMAL METRIC		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case(1)			1.3	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient(1)(2)			50	

(1) $R_{\theta JC}$ is determined with the device mounted on a 1 inch^2 (6.45 cm^2), 2 oz. (0.071 mm thick) Cu pad on a 1.5 inch × 1.5 inch (3.81 cm × 3.81 cm), 0.06 inch (1.52 mm) thick FR4 PCB. $R_{\theta JC}$ is specified by design, whereas $R_{\theta JA}$ is determined by the user's board design.
(2) Device mounted on FR4 material with 1 inch^2 (6.45 cm^2), 2 oz. (0.071 mm thick) Cu.

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Max $R_{\theta JA}$ = 50°C/W when mounted on 1 inch^2 (6.45 cm^2) of 2 oz. (0.071 mm thick) Cu.



Max $R_{\theta JA}$ = 125°C/W when mounted on a minimum pad area of 2 oz. (0.071 mm thick) Cu.

5.3 Typical MOSFET Characteristics

(T_A = 25°C unless otherwise stated)

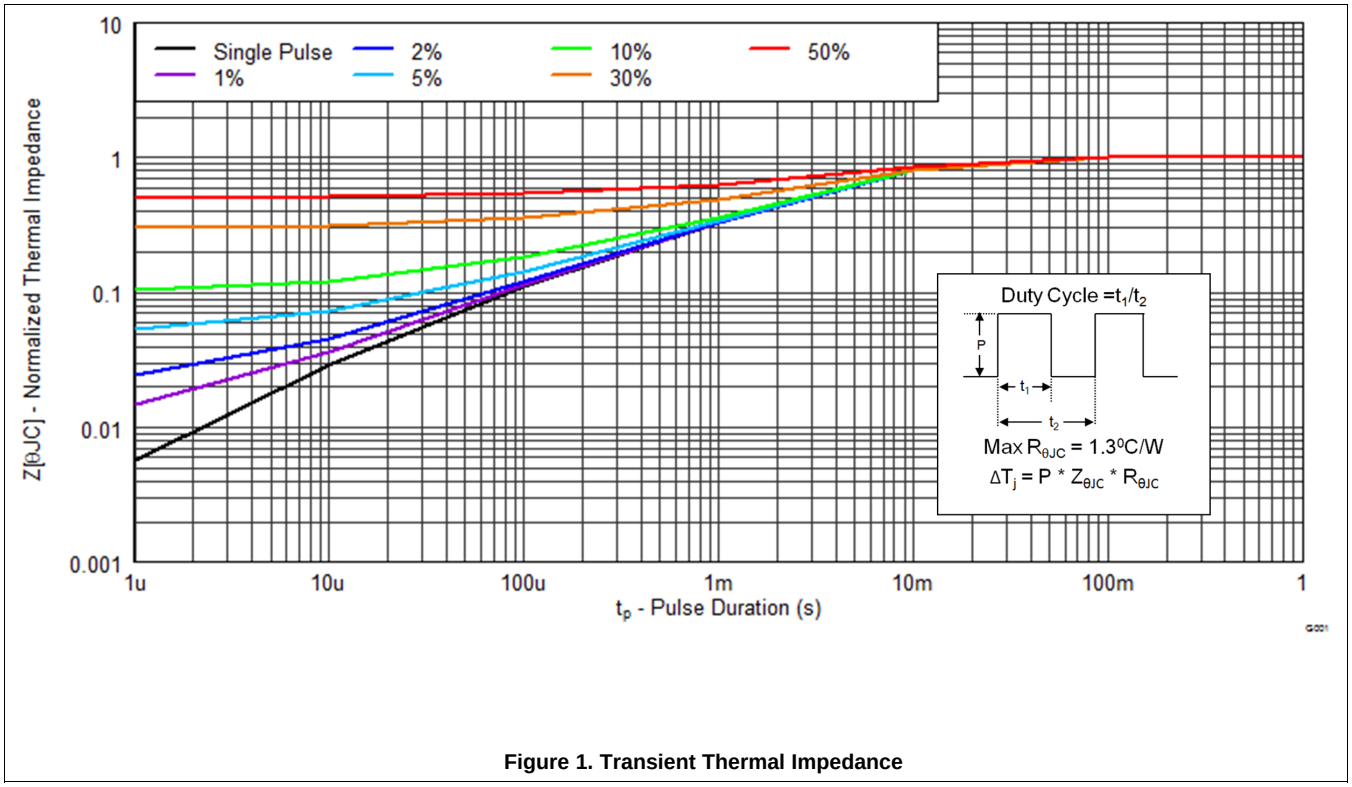


Figure 1. Transient Thermal Impedance

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Typical MOSFET Characteristics (continued)

(T_A = 25°C unless otherwise stated)

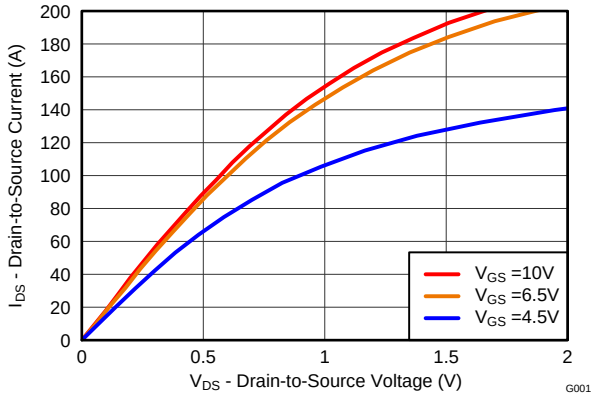


Figure 2. Saturation Characteristics

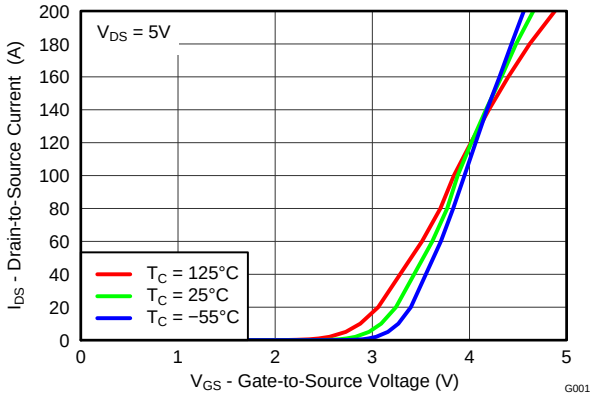


Figure 3. Transfer Characteristics

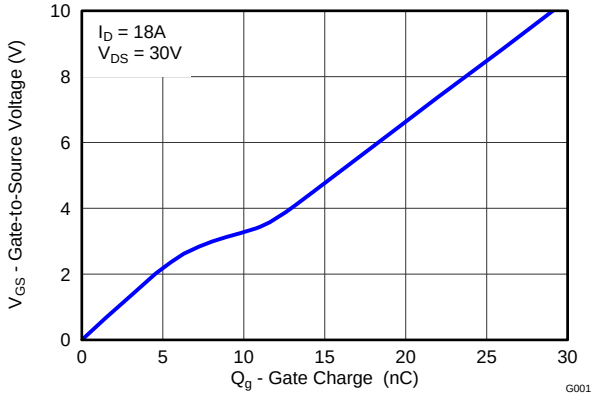


Figure 4. Gate Charge

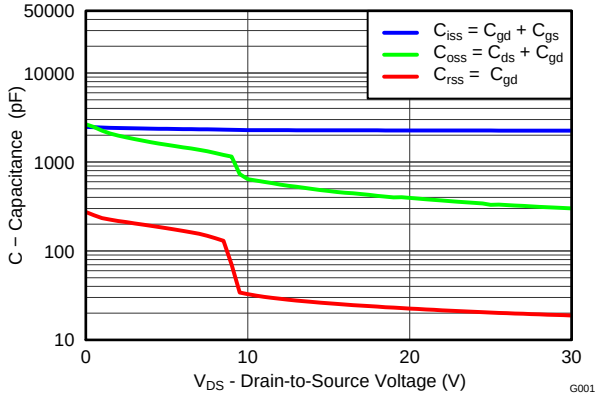


Figure 5. Capacitance

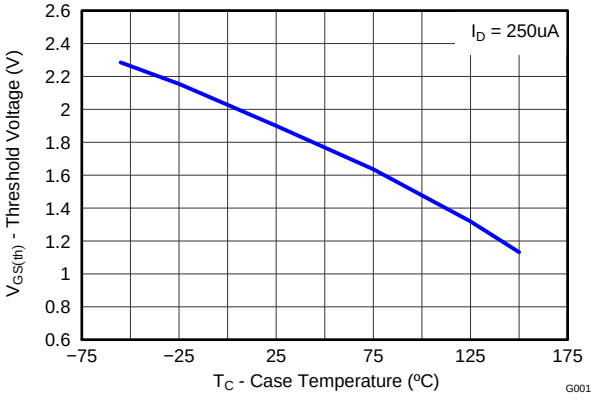


Figure 6. Threshold Voltage vs Temperature

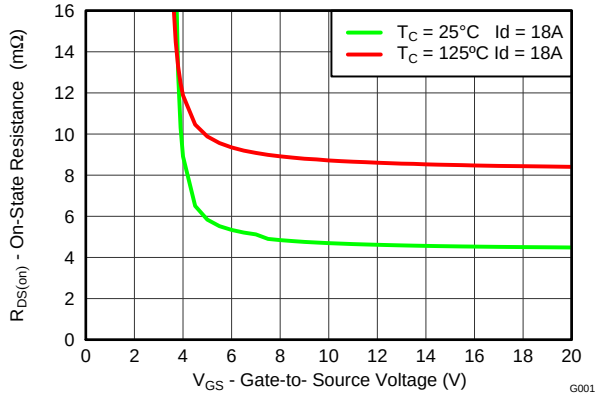


Figure 7. On-State Resistance vs Gate-to-Source Voltage

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Typical MOSFET Characteristics (continued)

(T_A = 25°C unless otherwise stated)

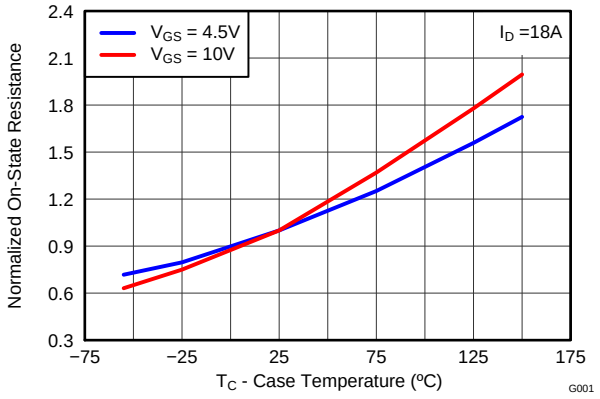


Figure 8. Normalized On-State Resistance vs Temperature

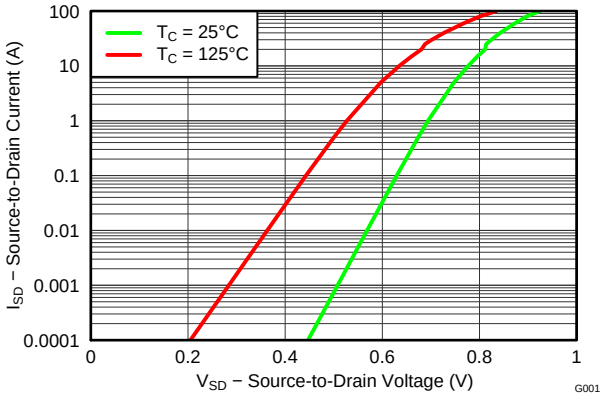


Figure 9. Typical Diode Forward Voltage

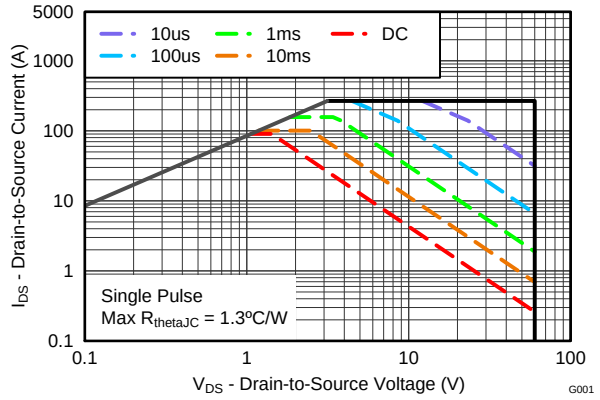


Figure 10. Maximum Safe Operating Area

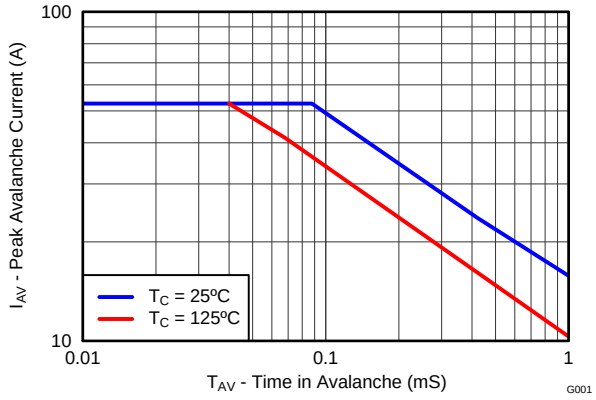


Figure 11. Single Pulse Unclamped Inductive Switching

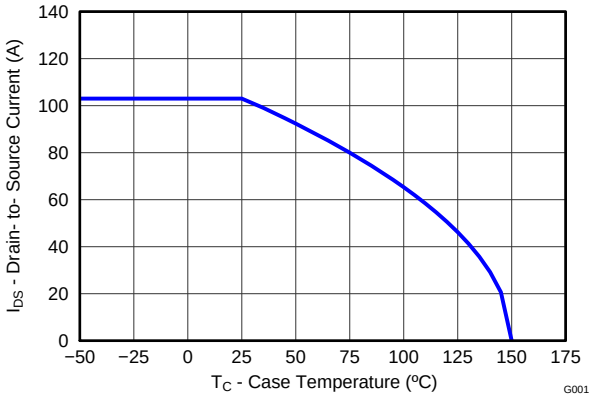


Figure 12. Maximum Drain Current vs Temperature

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6 器件和文档支持

6.1 商标

NexFET is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

6.2 静电放电警告



这些装置包含有限的内置 ESD 保护。 存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

6.3 术语表

SLYZ022 — *TI 术语表*。

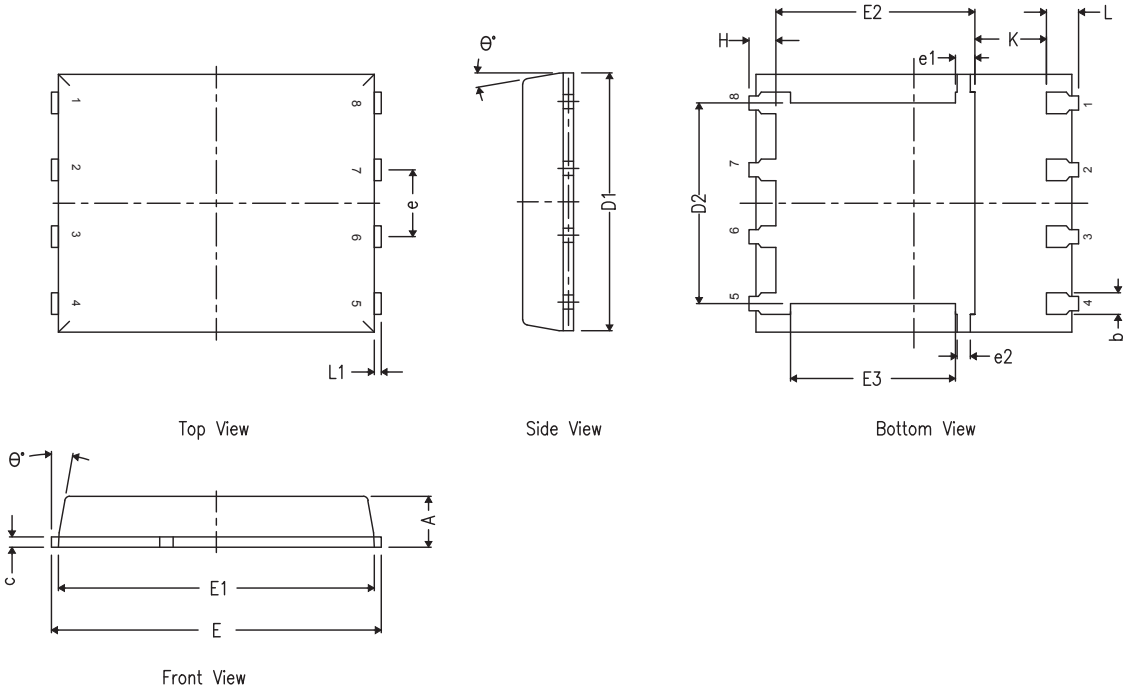
这份术语表列出并解释术语、首字母缩略词和定义。

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7 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。 这些信息是针对指定器件可提供的最新数据。 这些数据会在无通知且不对本文档进行修订的情况下发生改变。 欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

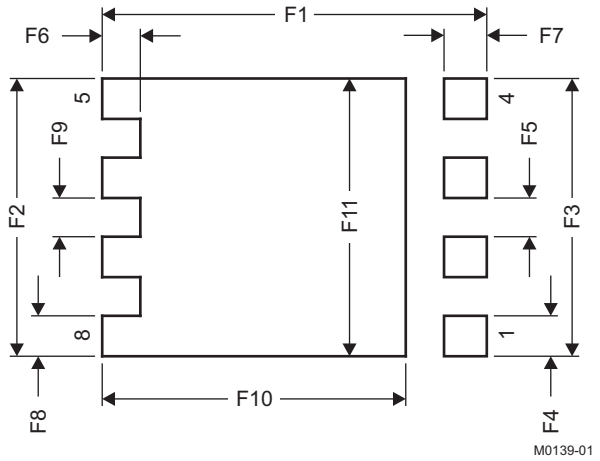
7.1 Q5A 封装尺寸



DIM	毫米		
	最小值	标称值	最大值
A	0.90	1.00	1.10
b	0.33	0.41	0.51
c	0.20	0.25	0.34
D1	4.80	4.90	5.00
D2	3.61	3.81	4.02
E	5.90	6.00	6.10
E1	5.70	5.75	5.80
E2	3.38	3.58	3.78
E3	3.03	3.13	3.23
e	1.17	1.27	1.37
e1	0.27	0.37	0.47
e2	0.15	0.25	0.35
H	0.41	0.56	0.71
K	1.10		
L	0.51	0.61	0.71
L1	0.06	0.13	0.20
θ	0°		12°

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7.2 建议印刷电路板 (PCB) 布局

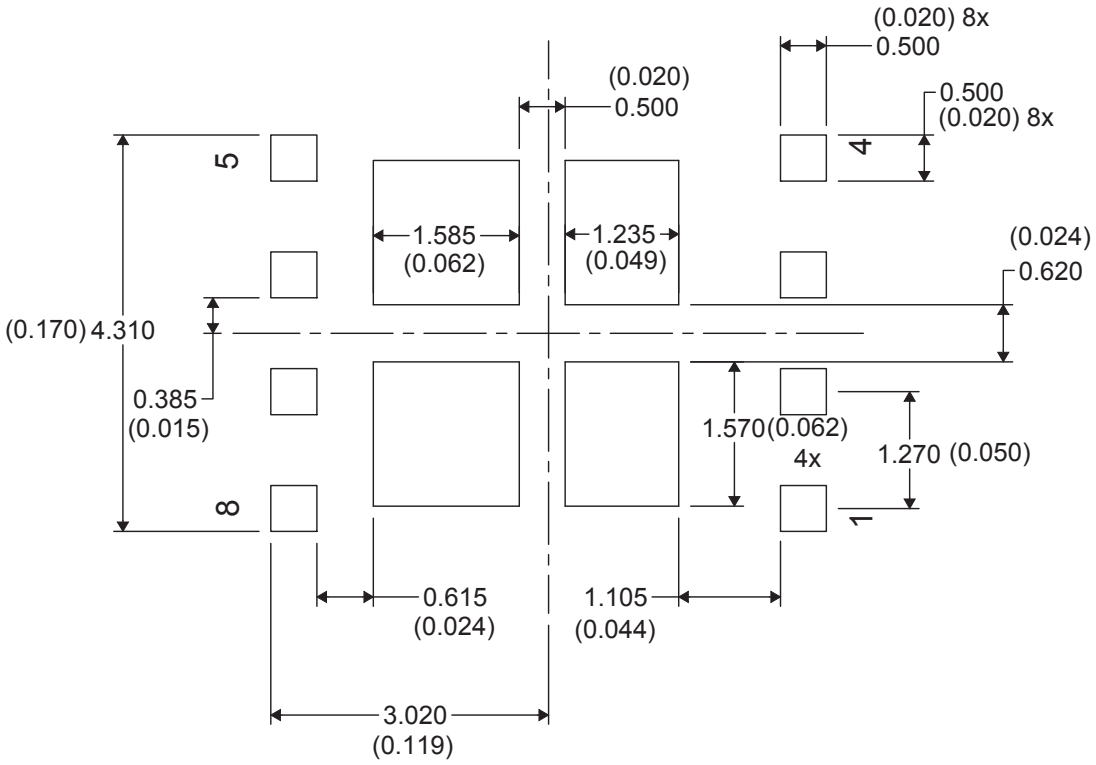


建议印刷电路板 (PCB) 布局 (接下页)

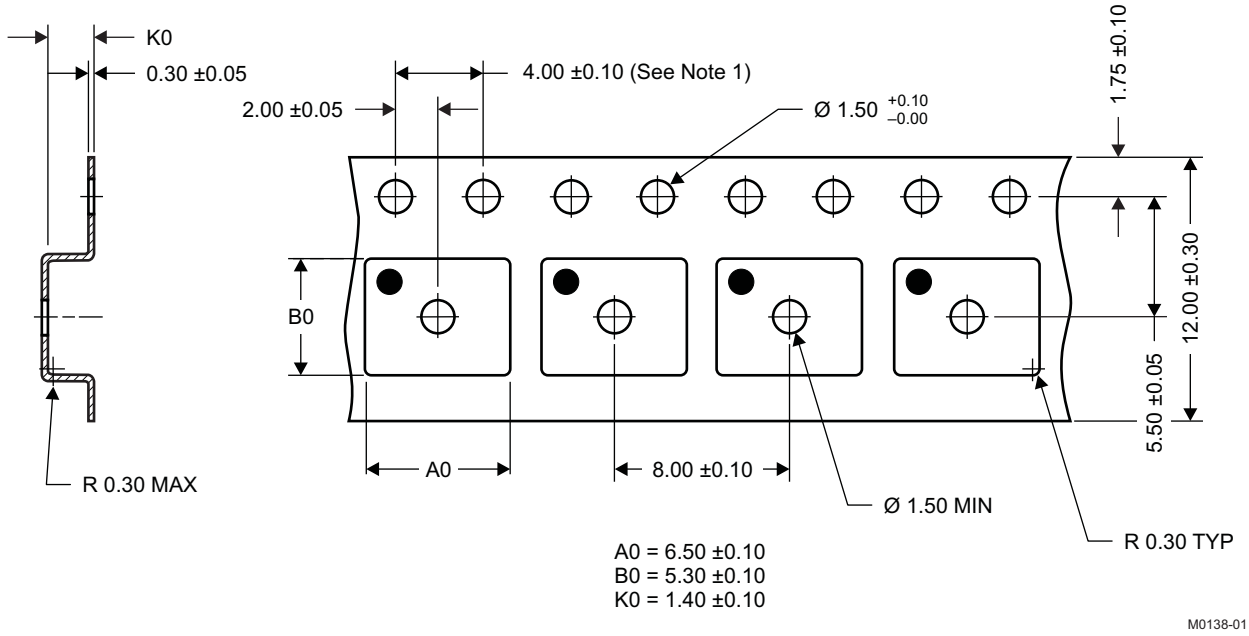
DIM	毫米		英寸	
	最小值	最大值	最小值	最大值
F1	6.205	6.305	0.244	0.248
F2	4.46	4.56	0.176	0.18
F3	4.46	4.56	0.176	0.18
F4	0.65	0.7	0.026	0.028
F5	0.62	0.67	0.024	0.026
F6	0.63	0.68	0.025	0.027
F7	0.7	0.8	0.028	0.031
F8	0.65	0.7	0.026	0.028
F9	0.62	0.67	0.024	0.026
F10	4.9	5	0.193	0.197
F11	4.46	4.56	0.176	0.18

要获得与印刷电路板 (PCB) 设计相关的建议电路布局布线，请参见《应用说明》SLPA005 - *通过 PCB 布局布线技巧来减少振铃*。

7.3 建议模板开口



7.4 Q5A 卷带信息



注：

1. 10 个链齿孔的累积容差为 ±0.2
2. 每 100mm 长度的翘曲不能超过 1mm，在 250mm 长度上不累积
3. 材料：黑色抗静电聚苯乙烯
4. 全部尺寸单位为 mm（除非另外注明）
5. 高于孔眼底部 0.3mm 的平面上测量得到 A0 和 B0 值

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CSD18533Q5A	Active	Production	VSONP (DQJ) | 8	2500 | LARGE T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	CSD18533
CSD18533Q5A.B	Active	Production	VSONP (DQJ) | 8	2500 | LARGE T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	CSD18533
CSD18533Q5AT	Active	Production	VSONP (DQJ) | 8	250 | SMALL T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	CSD18533
CSD18533Q5AT.B	Active	Production	VSONP (DQJ) | 8	250 | SMALL T&R	ROHS Exempt	SN	Level-1-260C-UNLIM	-55 to 150	CSD18533

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

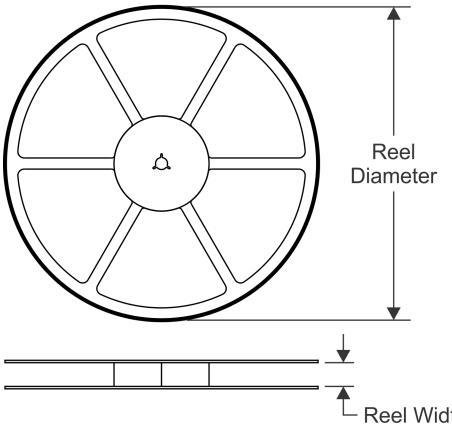
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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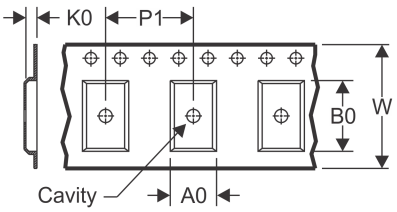
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TAPE AND REEL INFORMATION

REEL DIMENSIONS

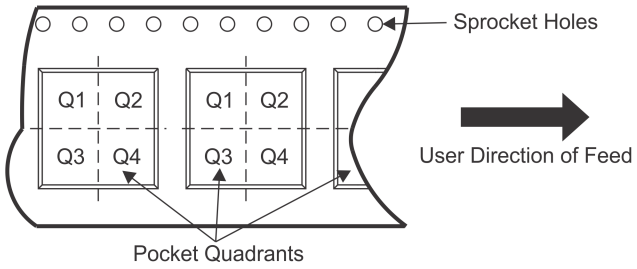


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

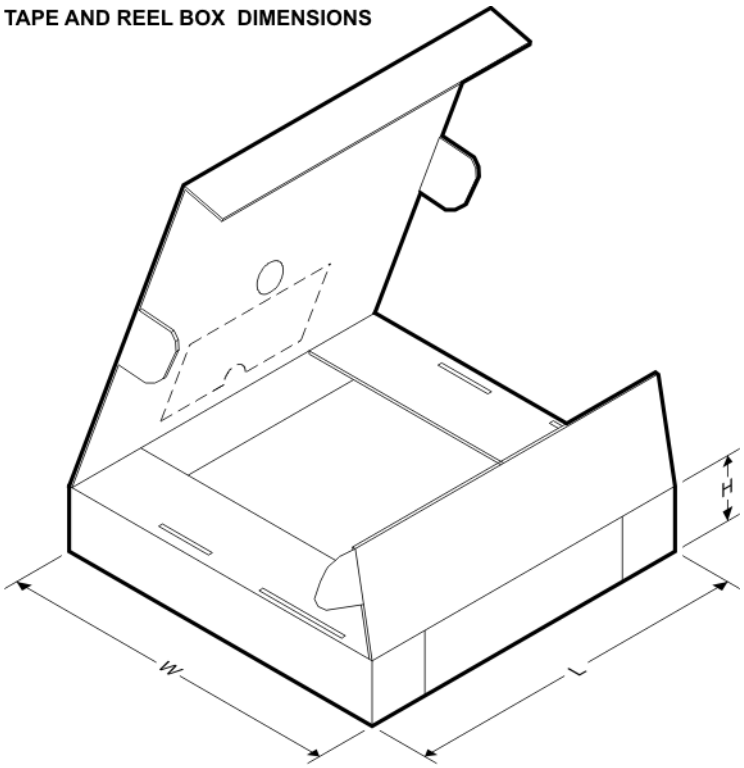
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD18533Q5A	VSONP	DQJ	8	2500	330.0	12.4	6.3	5.3	1.2	8.0	12.0	Q1
CSD18533Q5AT	VSONP	DQJ	8	250	180.0	12.4	6.3	5.3	1.2	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD18533Q5A	VSONP	DQJ	8	2500	340.0	340.0	38.0
CSD18533Q5AT	VSONP	DQJ	8	250	190.0	190.0	30.0

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